

# United States Patent and Trademark Office

UNITED STATES DEPARTMENT OF COMMERCE United States Patent and Trademark Office Address: COMMISSIONER FOR PATENTS P.O. Box 1450 Alexandria, Virginia 22313-1450 www.uspto.gov

APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO
10/781,684	02/20/2004	Hai-Zhi Song	040070	3691
23850	7590 11/17/2005		EXAMINER	
ARMSTRONG, KRATZ, QUINTOS, HANSON & BROOKS, LLP 1725 K STREET, NW			DICKEY, THOMAS L	
SUITE 1000	•		ART UNIT	PAPER NUMBER
WASHINGT	ON, DC 20006		2826	

DATE MAILED: 11/17/2005

Please find below and/or attached an Office communication concerning this application or proceeding.

3.181				W			
		Application No.	Applicant(s)	7			
Office Action Occurrence		10/781,684	SONG, HAI-ZHI				
	Office Action Summary	Examiner	Art Unit				
		Thomas L. Dickey	2826				
Period f	The MAILING DATE of this communication apports or Reply	pears on the cover sheet wi	th the correspondence add	ress			
THE - Extrafte - If th - If N - Fail	HORTENED STATUTORY PERIOD FOR REPL MAILING DATE OF THIS COMMUNICATION. ensions of time may be available under the provisions of 37 CFR 1.1 or SIX (6) MONTHS from the mailing date of this communication. e period for reply specified above is less than thirty (30) days, a repl O period for reply is specified above, the maximum statutory period ure to reply within the set or extended period for reply will, by statute or reply received by the Office later than three months after the mailing patent term adjustment. See 37 CFR 1.704(b).	136(a). In no event, however, may a rely within the statutory minimum of thirt will apply and will expire SIX (6) MON e, cause the application to become AB	eply be timely filed y (30) days will be considered timely. THS from the mailing date of this come ANDONED (35 U.S.C. § 133).	imunication.			
Status							
1)🖂	Responsive to communication(s) filed on 29 S	September 2005.					
2a) <u></u>	This action is <b>FINAL</b> . 2b)⊠ This	s action is non-final.					
3)							
Disposi	tion of Claims						
4)⊠	Claim(s) <u>1-16</u> is/are pending in the application.						
	4a) Of the above claim(s) <u>12-16</u> is/are withdrawn from consideration.						
5)	Claim(s) is/are allowed.						
6)⊠	Claim(s) <u>1-9 and 11</u> is/are rejected.						
7)🖂	Claim(s) <u>10</u> is/are objected to.						
8)[	Claim(s) are subject to restriction and/or election requirement.						
Applicat	tion Papers						
9)[	The specification is objected to by the Examine	er.					
10)🛛	0)⊠ The drawing(s) filed on <u>20 February 2004</u> is/are: a)⊠ accepted or b)□ objected to by the Examiner.						
	Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).  Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).						
11)	The oath or declaration is objected to by the Ex	xaminer. Note the attached	Office Action or form PTC	)-152.			
Priority	under 35 U.S.C. § 119						
	Acknowledgment is made of a claim for foreign All b) Some * c) None of:  1. Certified copies of the priority document 2. Certified copies of the priority document 3. Copies of the certified copies of the priority application from the International Burea	ts have been received. ts have been received in A rity documents have been	pplication No	tage			
* .	See the attached detailed Office action for a list	` ' ' ' '	received.				
Attachmei	• •	_					
	ce of References Cited (PTO-892)		ummary (PTO-413) )/Mail Date				
3) 🔲 Infoi	ce of Draftsperson's Patent Drawing Review (PTO-948) mation Disclosure Statement(s) (PTO-1449 or PTO/SB/08) er No(s)/Mail Date		formal Patent Application (PTO-1	52)			

Application/Control Number: 10/781,684 Page 2

Art Unit: 2826

## **DETAILED ACTION**

## Continued Examination Under 37 CFR 1.114

1. A request for continued examination under 37 CFR 1.114, including the fee set forth in 37 CFR 1.17(e), was filed in this application after final rejection. Since this application is eligible for continued examination under 37 CFR 1.114, and the fee set forth in 37 CFR 1.17(e) has been timely paid, the finality of the previous Office action has been withdrawn pursuant to 37 CFR 1.114. Applicant's submission filed on 09/29/2005 has been entered.

#### Oath/Declaration

**2.** The oath/declaration filed on 02/20/2004 is acceptable.

## **Drawings**

3. The formal drawings filed on 02/20/2004 are acceptable.

## **Priority**

**4.** Receipt is acknowledged of papers submitted under 35 U.S.C. 119(a)-(d), which papers have been placed of record in the file.

Application/Control Number: 10/781,684 Page 3

Art Unit: 2826

#### Information Disclosure Statement

5. The Information Disclosure Statement filed on 02/20/2004 has been considered.

## Claim Rejections - 35 USC § 102

**6.** The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless --

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

Claims 1-9 and 11 are rejected under 35 U.S.C. 102(b) as being anticipated by JAIN ET AL. (6,498,360).

With regard to claims 1-9 Jain et al. discloses a quantum semiconductor device with a first semiconductor layer 20 formed on a substrate 10 and having a two-dimensional carrier gas 19 formed in; a quantum dot 25 (quantum dot 25 and dot-shaped structure 23 are referred to generically as "coupled sub-wells," but claimed specifically as quantum dots in claim 25) formed on the first semiconductor layer 20; a second semiconductor layer 24 formed on the first semiconductor layer 20 and covering the quantum dot 25; a dot-shaped structure 23, being another (coupled") quantum dot, formed on the surface of the second semiconductor layer 24 at a position above the quantum dot 25, source 14/drain 15 regions connected to both ends of a channel region

Art Unit: 2826

defined by depletion regions formed in a regions of the first semiconductor layer 20 which are below oxide layers 21 and 22 formed on both sides of the dot-shaped structure 23 on the upper surface of the second semiconductor layer 24; and a gate electrode 17 connected to the dot-shaped structure 23; wherein the thickness of second semiconductor layer 24 (which separates quantum dot 25 and dot-shaped structure 23) is 15 angstroms, thus defining a distance between the two-dimensional carrier gas and the quantum dot 25 of 5 nm (50 angstroms) or less. Note figures 2,8,9, column 3 lines 15-20,53-54, column 4 lines 17-20, and column 6 lines 25-29 and 53-54 of Jain et al.

The applicant's claims 2-5 does not distinguish over the Jain et al. reference regardless of the process used to form the quantum dot 25 and dot-shaped structure 23, because only the final product is relevant, not the recited processes of forming the dot-shaped structure by generating crystal strains in the surface of the second semiconductor layer, or self-assembling the quantum dot and the dot-shaped structure by S-K mode.

Note that a "product by process" claim is directed to the product per se, no matter how actually made. In re Hirao, 190 USPQ 15 at 17 (footnote 3). See also In re Brown, 173 USPQ 685; In re Luck, 177 USPQ 523; In re Fessmann, 180 USPQ 324; In re Avery, 186 USPQ 161; In re Wertheim, 191 USPQ 90 (209 USPQ 554 does not deal with this issue); and In re Marosi et al., 218 USPQ 289, all of which make it clear that it is the patentability of the final product per se which must be determined in a "product by

Art Unit: 2826

process" claim and not the patentability of the process, and that an old or obvious product produced by a new method is not patentable as a product, whether claimed in "product by process" claims or not. Note that applicant has the burden of proof in such cases, as the above caselaw makes clear. See also MPEP 706.03(e).

With regard to claim 11, which is a necessary method of making the quantum semiconductor device of claim 1, Jain et al. discloses a method of making said quantum semiconductor device comprising the steps of forming on a substrate 10 a first semiconductor layer 20 with a two-dimensional carrier gas 19 formed in; forming a quantum dot 25 on the first semiconductor layer 20; forming a second semiconductor layer 24, covering the quantum dot 25; forming a dot-shaped structure 23 on the surface of the second semiconductor at a position above the quantum dot 25 due to strains generated in the surface of the second semiconductor layer 24 due to the presence of the quantum dot 25; and forming oxide layers 21 and 22 on both sides of the dot-shaped structure 23 on the upper surface of the second semiconductor layer 24. Note figures 2,8,9, column 3 lines 15-20,53-54, column 4 lines 17-20, and column 6 lines 25-29 and 53-54 of Jain et al.

Application/Control Number: 10/781,684 Page 6

Art Unit: 2826

## Allowable Subject Matter

7. Claim 10 is objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

## Response to Arguments

1. Applicant's arguments with respect to claims 1-9 and 11 have been considered but are most in view of the new ground(s) of rejection.

#### Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Thomas L Dickey whose telephone number is 571-272-1913. The examiner can normally be reached on Monday-Thursday 8-6.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Nathan J Flynn can be reached on 571-272-1915. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For

Art Unit: 2826

more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Thomas L. Dickey Patent Examiner Art Unit 2826

11/05